

- A → chassis 1500 MΩ
- B → chassis 1200 MΩ
- C → chassis 3000+ MΩ
- D → chassis 3000+ MΩ
- PQ → chassis 8 MΩ (3000 MΩ @ 1 KV)
- RU → chassis 3000 MΩ
- X → chassis 3000+ MΩ
- ⊙
- GOK bias → chassis 3000 MΩ
- EE → chassis 3000+ MΩ
- Einzel → chassis 3000+ MΩ
- anode "F" → chassis 3000+ MΩ

Tested @ 5KV Megohmmeter.  
2016-06-02

by David Wang